ENT COOPERATION TREAT P

From the INTERNATIONAL BUREAU **PCT** Commissioner **NOTIFICATION OF ELECTION US Department of Commerce** United States Patent and Trademark (PCT Rule 61.2) Office, PCT 2011 South Clark Place Room CP2/5C24 Arlington, VA 22202 Date of mailing (day/month/year) **ETATS-UNIS D'AMERIQUE** 04 July 2001 (04.07.01) in its capacity as elected Office International application No. Applicant's or agent's file reference PCT/US00/21377 3708 PCT International filing date (day/month/year) Priority date (day/month/year) 04 August 2000 (04.08.00) 06 August 1999 (06.08.99) **Applicant** MOFFATT, Stephen 1. The designated Office is hereby notified of its election made: in the demand filed with the International Preliminary Examining Authority on: 20 February 2001 (20.02.01) in a notice effecting later election filed with the International Bureau on: 2. The election was was not made before the expiration of 19 months from the priority date or, where Rule 32 applies, within the time limit under

Authorized officer The International Bureau of WIPO 34, chemin des Colombettes H. Zhou 1211 Geneva 20, Switzerland Facsimile No.: (41-22) 740.14.35 Telephone No.: (41-22) 338.83.38 Form PCT/IB/331 (July 1992)

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INTERNATIONAL PRELIMINARY EXAMINATION REPORT

(PCT Article 36 and Rule 70)

Applicant's or agent's file reference		
3708/CT/203.24	FOR FURTHER ACTION	See Notification of Transmittal of International Preliminary Examination Report (Form
International application No.	International filing date (day/m	nonth/year) Priority date (day/month/year)
PCT/US00/21877	04 AUGUST 2000	06 AUGUST 1999
International Patent Classification (IPC) IPC(7): A61N 5/00; G21G 5/00 and U	or national classification and IPO JS Cl.: 250/492.2	
Applicant APPLIED MATERIAL, INC.		
2. This REPORT consists of a t This report is also accomp been amended and are the	total of sheets. anied by ANNEXES, i.e., sheets basis for this report and/or sheet	s of the description, claims and/or drawings which have
These annexes consist of a total	in our of the Administrative In	structions under the PCT).
3. This report contains indications		ms.
IV Lack of unity of in V X Reasoned statement	t of report with regard to nove	elty, inventive step or industrial applicability l to novelty, inventive step or industrial applicability;
VI Certain documents ci		u.
VII Certain defects in the	e international application	
VIII Certain observations	on the international applicatio	n
Date of submission of the demand	Date of	completion of this report
20 FEBRUARY 2001		UGUST 2001
lame and mailing address of the IPEA/US Commissioner of Patents and Trademark Box PCT Washington, D.C. 20231	s	ed officer Skarm S. Noppl ESA ARROYO
acsimile No. (703) 305-3230	Telephon	ne No. (703) 308–0956
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Form PCT/IPEA/409 (cover sheet) (July 1998)*

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

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1	Int	ional application No.
	PCT	/US00/21377

I. B	asis of	the report						
1 Wir	h regard (to the elements of the inter	mational analisasi	i				
	-	ernational application						
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	the lang the lang	uage of a translation fi uage of publication of	urnished for the	ne purposes o nal applicatio	f international se n (under Rule 48	earch (und 3.3(b)).	which er Rule 23.1(b)).	
3. With	n regard iminary	to any nucleotide and/ o examination was carrie d in the international a	d out on the b	asis of the se	closed in the interquence listing:	national ap	oplication, the internation	nal
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4. X		endments have resulted	in the cancell	lation of:				
اِ	X the	description, pages	NONE					
L	X the	claims, Nos.	NONE					
Γ		drawings, sheets/fig	NONE					
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		ent sheet containing suc	h amendments n	must be referr	ed to under item	I and anne	exed to this report	

INTERNATIONAL PRELIMINARY EXAMINATION REPORT

statement		
Novelty (N)	Claims	1-40
	Claims	NONE
Inventive Step (IS)	Claims	1-40
22 (24) (15)	Claims	NONE
Industrial Applicability (IA)	Claims	1-40
	Claims	NONE
the notice, and exposing the	e layer to a chai	estrate comprising the steps of forming the layer, positioning eged particle.
ONE NEW CITATIONS ———		



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INTERNATIONAL SEARCH REPORT

(PCT Article 18 and Rules 43 and 44)

Applicant's or agent's file reference 3708 PCT	FOR FURTHER See No ACTION (Form F	tification of Transmittal of International Search Report PCT/ISA/220) as well as, where applicable, item 5 below.
International application No.	International filing date (day/month	/year) (Earliest) Priority Date (day/month/year)
PCT/US 00/21377	04/08/2000	06/08/1999
APPLIED MATERIALS, INC. et	prepared by this International Second	hing Authority and is transmitted to the applicant
This International Search Report consists of	and de la contraction de la co	rs.
1. Basis of the report		
 With regard to the language, the in language in which it was filed, unlest 	ternational search was carried out or ss otherwise indicated under this item	n the basis of the international application in the
		tion of the international application furnished to this
contained in the internation	or amino acid sequence disclosed sequence listing: sequence listing: al application in written form. ational application in computer reada	in the international application, the international search
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	nis Authority in computer readble form	1.
the statement that the subse international application as t	equently furnished written sequence li iled has been furnished.	isting does not go beyond the disclosure in the
the statement that the inform furnished	nation recorded in computer readable	form is identical to the written sequence listing has been
2. Certain claims were found	unsearchable (See Box I).	
3. X Unity of invention is lacking	g (see Box II).	
4. With regard to the title ,		
X the text is approved as subm	itted by the applicant	
	by this Authority to read as follows:	
5. With regard to the abstract, [X] the text is approved as subm	itted by the applicant.	
	o a management ocall	uthority as it appears in Box III. The applicant may, ch report, submit comments to this Authority.
 The figure of the drawings to be published 	d with the abstract is Figure No.	3
as suggested by the applican		None of the figures.
because the applicant failed t		
because this figure better cha	racterizes the invention.	

INTERNATIONAL SEARCH REPORT

International application No. PCT/US 00/21377

Box I Observations where certain claims were found unsearchable (Continuation of item 1 of first sheet)	
This International Search Report has not been established in respect of certain claims under Article 17(2)(a) for the following reasons:	
1. Claims Nos.: because they relate to subject matter not required to be searched by this Authority, namely:	
Claims Nos.: because they relate to parts of the International Application that do not comply with the prescribed requirements to such an extent that no meaningful International Search can be carried out, specifically:	
3. Claims Nos.: because they are dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).	
Box II Observations where unity of invention is lacking (Continuation of item 2 of first sheet)	
This International Searching Authority found multiple inventions in this international application, as follows:	\dashv
see additional sheet	
As all required additional search fees were timely paid by the applicant, this International Search Report covers all searchable claims.	
2. As all searchable claims could be searched without effort justifying an additional fee, this Authority did not invite payment of any additional fee.	
3. As only some of the required additional search fees were timely paid by the applicant, this International Search Report covers only those claims for which fees were paid, specifically claims Nos.:	
A. No required additional search fees were timely paid by the applicant. Consequently, this International Search Report is restricted to the invention first mentioned in the claims; it is covered by claims Nos.: 1-9,11-14,17,18	
The additional search fees were accompanied by the applicant's protest. No protest accompanied the payment of additional search fees.	
orm PCT/ISA/210 (continuation of first short (4)) (11)	

International Application No. PCT/US 00/21377

FURTHER INFORMATION CONTINUED FROM PCT/ISA/ 210

This International Searching Authority found multiple (groups of) inventions in this international application, as follows:

1. Claims: 1-9,11-14,17,18

A wafer holder for retaining a substrate within a process chamber, comprising:

- an electrode, so that the wafer holder can also be called electrostatic chuck; and
- one or more layers covering a portion of the wafer holder in contact with the wafer, where at least one of the layers is compliant.

An apparatus for projecting patterned charged particles onto a substrate, comprising:

- a processing chamber;
- a charged particle source for generating a charged particle beam that impinges on the substrate; and
- an electrostatic chuck as described above.

2. Claims: 10,15,16

An apparatus for projecting patterned charged particles onto a substrate, comprising:

- a processing chamber;
- a charged particle source for generating a charged particle beam that impinges on the substrate;
- an electrostatic chuck comprising an electrode and one or more layers covering a portion of the wafer holder in contact with the wafer where at least one of the layers is compliant; and comprising:
- a computer for calculating an estimated charged particle beam deflection to compensate for the actual deformation of the substrate, wherein the computer generates a deflection signal corresponding to the calculated deflection;
- a beam deflector for deflecting the charged particle beam in response to the deflection signal from the computer; or comprising:
- a lithography mask between the charged particle source and the substrate;
- an electron sensor for detecting backscattered electrons;

International Application No. PCT/US 00 /21377

FURTHER INFORMATION CONTINUED FROM PCT/ISA/ 210

or comprising:

- a substrate temperature sensor for sending a signal corresponding to the measured substrate temperature to the computer.

3. Claims: 19-25

A method for patterning a photoresist layer on a substrate comprising the steps of:

- forming a photoresist layer on the substrate;
- positioning the substrate on an electrostatic chuck having one or more layers covering a portion of the wafer holder in compliant; and
- exposing portions of the photoresist layer on the substrate to a charged particle beam.

4. Claims: 26-28

An electrostatic chuck for use in substrate processing, the chuck having an electrode covered by an insulative layer for receiving the substrate, wherein the insulative layer is elastic and can withstand 10% shear stress without exceeding the material yield strength.

5. Claims: 29-35

A method for holding a wafer on a chuck having an electrode and one or more layers covering a portion of the wafer holder in contact with the wafer where at least one of the layers is compliant, comprising the steps of:

- placing the wafer on one of the layers of the chuck; and
- energizing the electrode.

6. Claims: 36-40

An apparatus for handling a substrate for use in semiconductor processing, comprising:

- a wafer holder; and
- one or more layers covering a portion of the wafer holder in contact with the wafer where at least one of the layers is compliant.

	FURTHER INCORMATION CONTINUES -			International Application No. PCI/US	00/21377
	FURTHER INFORMATION CONTINUED FROM	PCT/ISA/	210		
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INTERNATIONAL SEARCH REPORT

International Application No

PCT/US 00/21377 A. CLASSIFICATION OF SUBJECT MATTER IPC 7 H01L21/00 According to International Patent Classification (IPC) or to both national classification and IPC **B. FIELDS SEARCHED** Minimum documentation searched (classification system followed by classification symbols) IPC 7 H01L Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched Electronic data base consulted during the international search (name of data base and, where practical, search terms used) EPO-Internal, WPI Data, PAJ, IBM-TDB, INSPEC C. DOCUMENTS CONSIDERED TO BE RELEVANT Category ° Citation of document, with indication, where appropriate, of the relevant passages Relevant to claim No. Х US 5 452 177 A (FRUTIGER WILLIAM A) 1,2,5,6, 19 September 1995 (1995-09-19) 8,9,13, 14, 26-30, 33,34, 36,37,39 Α column 4, line 40 - line 55 column 6, line 50 - line 63 column 7, line 31 - line 64 column 9, line 35 - line 50 Further documents are listed in the continuation of box C. Patent family members are listed in annex. Special categories of cited documents: "T" later document published after the international filing date or priority date and not in conflict with the application but cited to understand the principle or theory underlying the "A" document defining the general state of the art which is not considered to be of particular relevance earlier document but published on or after the international "X" document of particular relevance; the claimed invention cannot be considered novel or cannot be considered to document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other special reason (as specified) involve an inventive step when the document is taken alone "Y" document of particular relevance; the claimed invention cannot be considered to involve an inventive step when the document is combined with one or more other such docudocument referring to an oral disclosure, use, exhibition or ments, such combination being obvious to a person skilled document published prior to the international filing date but in the art. later than the priority date claimed "&" document member of the same patent family Date of the actual completion of the international search Date of mailing of the international search report 1 5. 06. 01 10 January 2001 Name and mailing address of the ISA Authorized officer European Patent Office, P.B. 5818 Patentlaan 2 NL - 2280 HV Rijswijk Tel. (+31-70) 340-2040, Tx. 31 651 epo nl, Fax: (+31-70) 340-3016 Giordani, S

INTERNATIONAL SEARCH REPORT

International Application No PCT/US 00/21377

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International Application No

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(12) INTERNATIONAL APPLICATION PUBLISHED UNDER THE PATENT COOPERATION TREATY (PCT)

(19) World Intellectual Property Organization International Bureau



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(43) International Publication Date 15 February 2001 (15.02.2001)

PCT

(10) International Publication Number WO 01/11431 A2

(51) International Patent Classification7:

G03F 7/20

(21) International Application Number: PCT/US00/21377

(22) International Filing Date: 4 August 2000 (04.08.2000)

(25) Filing Language:

English

(26) Publication Language:

English

(30) Priority Data:

60/147,684

6 August 1999 (06.08.1999) U

(71) Applicant (for all designated States except US): AP-PLIED MATERIALS, INC. [US/US]; 3050 Bowers Avenue, Santa Clara, CA 95054 (US).

(72) Inventor; and

(75) Inventor/Applicant (for US only): MOFFATT, Stephen

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(74) Agent: DERGOSITS, Michael; Dergosits & Noah LLP, Suite 1150, Four Embarcadero Center, San Francisco, CA 94111 (US).

(81) Designated States (national): JP, KP, US.

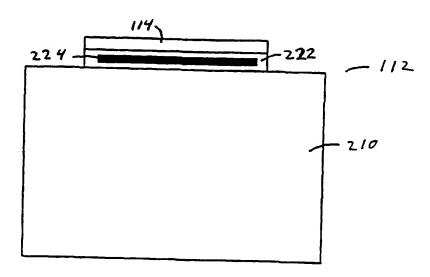
(84) Designated States (regional): European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE).

Published:

 Without international search report and to be republished upon receipt of that report.

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: METHOD AND APPARATUS OF HOLDING SEMICONDUCTOR WAFERS FOR LITHOGRAPHY AND OTHER WAFER PROCESSES



(57) Abstract: A wafer chuck is designed to allow the substrate to thermally deform during charged particle beam lithography. The wafer chuck includes a compliant layer disposed over a chuck body. During lithography processing the wafer is electrostatically held in contact with a flexible compliant layer and the wafer is exposed to the charged particle beam resulting in thermal deformation of the wafer. The compliant layer deforms with the substrate and allows the wafer to deform in a predictable manner.

O 01/11431 A2

(19) World Intellectual Property Organization International Bureau



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(43) International Publication Date 15 February 2001 (15.02.2001)

PCT

(10) International Publication Number WO 01/11431 A3

(51) International Patent Classification7:

- 01

(A4) Y

(21) International Application Number: PCT/US00/21377

(22) International Filing Date: 4 August 2000 (04.08.2000)

(25) Filing Language:

English

H01L 21/00

(26) Publication Language:

English

(30) Priority Data: 60/147,684

6 August 1999 (06.08.1999) [

(71) Applicant (for all designated States except US): AP-PLIED MATERIALS, INC. [US/US]; 3050 Bowers Avenue, Santa Clara, CA 95054 (US).

(72) Inventor; and

(75) Inventor/Applicant (for US only): MOFFATT, Stephen [GB/US]; 3544 Washington Boulevard, Jersey City, NJ 07310 (US).

(74) Agent: DERGOSITS, Michael; Dergosits & Noah LLP, Suite 1150, Four Embarcadero Center, San Francisco, CA 94111 (US).

(81) Designated States (national): JP, KP, US.

(84) Designated States (regional): European patent (AT, BE, CH, CY, DE, DK, ES, FI, FR, GB, GR, IE, IT, LU, MC, NL, PT, SE).

Published:

with international search report

with amended claims and statement

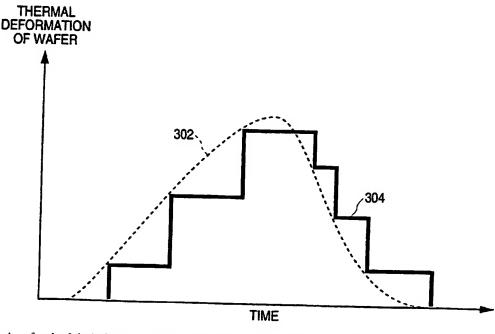
(88) Date of publication of the international search report:

15 November 2001

Date of publication of the amended claims and statement: 20 December 2001

For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: METHOD AND APPARATUS OF HOLDING SEMICONDUCTOR WAFERS FOR LITHOGRAPHY AND OTHER WAFER PROCESSES



(57) Abstract: A wafer chuck is designed to allow the substrate to thermally deform during charged particle beam lithography. The wafer chuck includes a compliant layer disposed over a chuck body. During lithography processing the wafer is electrostatically held in contact with a flexible compliant layer and the wafer is exposed to the charged particle beam resulting in thermal deformation of the wafer. The compliant layer deforms with the substrate and allows the wafer to deform in a predictable manner.



01/11431 A3

15

AMENDED CLAIMS

[received by the International Bureau on 15 August 2001 (15.08.01); original claims 1 and 8 amended; remaining claims unchanged (2 pages)]

- A wafer holder for retaining a substrate within a processing chamber comprising:
 an electrode; and
- one or more layers covering a portion of the wafer holder and having a compliant

 surface for supporting the substrate which moves with the substrate in a direction parallel
 to a planar surface of the substrate when the substrate expands or contracts.
 - 2. The chuck of claim 1 wherein the compliant layer has a hardness between 25 and 100 Shore Hardness scale A.
 - 3. The chuck of claim 1 wherein the compliant layer is an insulator having a dielectric constant between 1 and 3.
- 4. The chuck of claim 1 wherein the compliant layer can withstand 10% shear stress without exceeding the yield strength of the complaint layer material.
 - 5. The chuck of claim 1 wherein the electrode comprises at least one conductive material selected from the group consisting of: copper, nickel, chromium, aluminum iron, and mixtures or alloys thereof.
 - 6. The chuck of claim 1 wherein the compliant layer comprises an insulative material selected from the group consisting of: fluorosilicones, polyamides,

polyketones, polyetherketones, polysulfones, polycarbonates, polystyrenes, polyurethanes, nylons, polyvinylchlorides, polypropylenes, polyetherketones, polyethersulfones, polyethylene terephthalate, fluoroethylene propylene copolymers, cellulose, triacetates, silicones and rubbers, and combinations thereof.

- The chuck of claim 1 wherein the compliant layer is between 1 and 3 μm thick.
- 8. An apparatus for projecting patterned charged particles onto a substrate comprising:
- a processing chamber;
 - a charged particle source for generating a charged particle beam that impinges on the substrate; and

an electrostatic chuck comprising an electrode and one or more layers covering a portion of the wafer holder and having a compliant surface for supporting the substrate which moves with the substrate in a direction parallel to a planar surface of the substrate when the substrate expands or contracts.

- 9. The apparatus of claim 8 wherein the compliant layer has a hardness between 25 and 100 Shore Hardness scale A.
- 10. The apparatus of claim 8 further comprising:
- a computer for calculating an estimated charged particle beam deflection to compensate for the actual deformation of the substrate caused by the exposure of the

STATEMENT UNDER ARTICLE 19 (1)

In the International Search Report, the Examiner cited several references as being of particular relevance alone. All of these references disclose an electrostatic wafer support having an insulative layer which contacts the substrate. Applicant submits that although some of the cited references disclose a vertically compressible insulative layer, none of the references disclose a compliant layer that moves with the substrate in a direction parallel to a planar surface of the substrate as the substrate expands or contracts. In particular, during wafer processing, the temperature of the substrate tends to increase resulting in thermal expansion. A substrate surface is required which is mechanically stable elevated temperatures and sufficiently elastic to move with the expanding and contracting substrate.

The Examiner cited U.S. Patent Nos. 5,883,778, 5,729,423, 5,452,177, 5,310,453, 4,665,463, and European Patent Nos. 0856882 and 0692814, each as being of particular relevance alone. The applicant submits that while the references disclose a layer having vertical compliance, none of the references disclose a layer on a wafer holder having a compliant surface for supporting a substrate that expands or contracts in a direction parallel to the planar surface of the substrate.

III. Conclusion

It is respectfully submitted that the amended claims included on the attached substitute pages are novel and involve an inventive step that is not obvious to one skilled in the art in light of the cited references, either alone or in combination. It is further respectfully submitted that the amendments made to the claims do not amend or otherwise impact the description and drawings as originally filed.